

### LM431

# **Adjustable Precision Zener Shunt Regulator**

### **General Description**

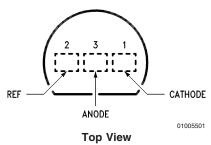
The LM431 is a 3-terminal adjustable shunt regulator with guaranteed temperature stability over the entire temperature range of operation. It is now available in a chip sized package (4-Bump micro SMD) using National's micro SMD package technology. The output voltage may be set at any level greater than 2.5V ( $V_{\rm REF}$ ) up to 36V merely by selecting two external resistors that act as a voltage divided network. Due to the sharp turn-on characteristics this device is an excellent replacement for many zener diode applications.

### **Features**

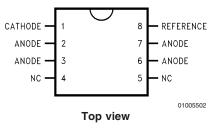
- Average temperature coefficient 50 ppm/°C
- Temperature compensated for operation over the full temperature range
- Programmable output voltage
- Fast turn-on response
- Low output noise
- LM431 in micro SMD package
- See AN-1112 for micro SMD considerations

### **Connection Diagrams**

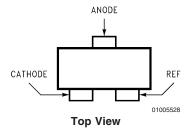
TO-92: Plastic Package



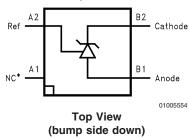
#### SO-8: 8-Pin Surface Mount



#### SOT-23: 3-Lead Small Outline



#### 4-Bump micro SMD



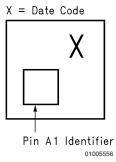
Note: \*NC = Not internally connected. Must be electrically isolated from the rest of the circuit for the microSMD package.

# **Ordering Information**

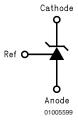
Package	Typical Accuracy Order Number/Package Marking			Temperature Range	Transport Media	NSC Drawing	
	0.5%	1%	2%	]			
TO-92	LM431CCZ/	LM431BCZ/	LM431ACZ/	0°C to +70°C			
	LM431CCZ	LM431BCZ	LM431ACZ	0 0 10 +70 0	Rails	Z03A	
	LM431CIZ/	LM431BIZ/	LM431AIZ/	-40°C to +85°C	Halls		
	LM431CIZ	LM431BIZ	LM431AIZ	-40 C to +65 C			
SO-8	LM431CCM/	LM431BCM/	LM431ACM/		Rails		
	431CCM	431BCM	LM431ACM	0°C to +70°C	nalis	M08A	
	LM431CCMX/	LM431BCMX/	LM431ACMX/	0 0 10 +70 0	Tape & Reel		
	431CCM	431BCM	LM431ACM		rape a neer		
	LM431CIM/	LM431BIM/	LM431AIM/		Rails		
	431CIM	431BIM	LM431AIM	-40°C to +85°C	naiis		
	LM431CIMX/	LM431BIMX/	LM431AIMX/	-40 0 10 +63 0	Tape &Reel		
	431CIM	431BIM	LM431AIM		Tape wheel		
SOT-23	LM431CCM3/	LM431BCM3/	LM431ACM3/		Rails	MF03A	
	N1B	N1D	N1F	0°C to +70°C	naiis		
	LM431CCM3X/	LM431BCM3X	LM431ACM3X/	0 0 10 +70 0	Tape & Reel		
	N1B	N1D	N1F		rape a neer		
	LM431CIM3	LM431BIM3	LM431AIM3		Rails		
	N1A	N1C	N1E	-40°C to +85°C	naiis		
	LM431CIM3X	LM431BIM3X	LM431AIM3X	-40 0 10 +63 0	Tape &Reel		
	N1A	N1C	N1E		Tape wheel		
micro SMD		_	LM431AIBP	–40°C to +85°C	250 Units Tape and	BPA04AFB	
	_		LM431AIBPX		Reel		
			(Note 1)	40 0 10 400 0	3k Units Tape and Reel	טו אסדאו ט	

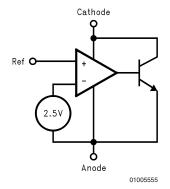
Note 1: The micro SMD package marking is a 1 digit manufacturing Date Code only

### micro SMD Top View Marking Example



# **Symbol and Functional Diagrams**





### **DC Test Circuits**

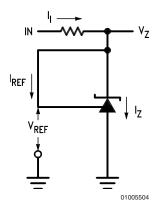
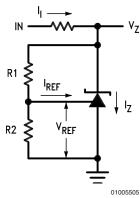
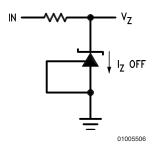


FIGURE 1. Test Circuit for  $V_Z = V_{REF}$ 



**Note:**  $V_Z = V_{REF} (1 + R1/R2) + I_{REF} R1$ 

FIGURE 2. Test Circuit for  $V_Z > V_{\rm REF}$ 



**Test Circuit for Off-State Current** 

### **Absolute Maximum Ratings** (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature Range -65°C to +150°C

Operating Temperature Range

Industrial (LM431xI)  $-40^{\circ}$ C to  $+85^{\circ}$ C Commercial (LM431xC)  $0^{\circ}$ C to  $+70^{\circ}$ C

Soldering Information

Infrared or Convection (20 sec.) 235°C

Wave Soldering (10 sec.) 260°C (lead temp.) Cathode Voltage 37V

Continuous Cathode Current -10 mA to +150

37V 150 mA Reference Voltage -0.5V
Reference Input Current 10 mA
Internal Power Dissipation (Notes 3,
4)
TO-92 Package 0.78W
SO-8 Package 0.81W

**Operating Conditions** 

SOT-23 Package

Cathode Voltage

Cathode Current

micro SMD Package

 Min
 Max

 V<sub>REF</sub>
 37V

 1.0 mA
 100 mA

0.28W

0.30W

### LM431 Electrical Characteristics

T<sub>A</sub> = 25°C unless otherwise specified

Symbol	Parameter	Parameter Conditions		Min	Тур	Max	Units
V <sub>REF</sub>	Reference Voltage	$V_Z = V_{REF}$ , $I_I = 10 \text{ mA}$		2.440	2.495	2.550	V
		LM431A (Figure 1)					
		$V_Z = V_{REF}$ , $I_I = 10 \text{ mA}$		2.470	2.495	2.520	V
		LM431B (Figure 1)					
		$V_Z = V_{REF}$ , $I_I = 10 \text{ mA}$		2.485	2.500	2.510	V
		LM431C (Figure 1)					
$V_{DEV}$	Deviation of Reference Input Voltage Over	$V_Z = V_{REF}$ , $I_I = 10 \text{ mA}$ ,			8.0	17	mV
	Temperature (Note 5)	T <sub>A</sub> = Full Range <i>(Figure 1</i> )					
$\Delta V_{REF}$	Ratio of the Change in Reference Voltage	I <sub>Z</sub> = 10 mA	V <sub>Z</sub> from V <sub>REF</sub> to 10V		-1.4	-2.7	mV/V
$\Delta V_Z$	to the Change in Cathode Voltage	(Figure 2)	V <sub>Z</sub> from 10V to 36V		-1.0	-2.0	
I <sub>REF</sub>	Reference Input Current	$R_1 = 10 \text{ k}\Omega, R_2 = \infty,$			2.0	4.0	μA
		I <sub>I</sub> = 10 mA <i>(Figure 2</i> )					
∝I <sub>REF</sub>	Deviation of Reference Input Current over	$R_1 = 10 \text{ k}\Omega, R_2 = \infty,$					
	Temperature	$I_I = 10 \text{ mA},$			0.4	1.2	μΑ
		T <sub>A</sub> = Full Range <i>(Figure 2</i> )					
$I_{Z(MIN)}$	Minimum Cathode Current for Regulation	$V_Z = V_{REF}$ (Figure 1)			0.4	1.0	mA
$I_{Z(OFF)}$	Off-State Current	$V_Z = 36V$ , $V_{REF} = 0V$ (Figure *NO			0.3	1.0	μΑ
		TARGET FOR fi*)					
$r_Z$	Dynamic Output Impedance (Note 6)	$V_Z = V_{REF}$ , LM431A,				0.75	Ω
		Frequency = 0 Hz (Figure 1)					
		$V_Z = V_{REF}$ , LM431B, LM431C				0.50	Ω
		Frequency = 0 Hz (Figure 1)					

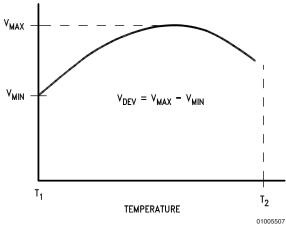
Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.

**Note 3:**  $T_{J \text{ Max}} = 150^{\circ} \text{C}.$ 

Note 4: Ratings apply to ambient temperature at 25°C. Above this temperature, derate the TO-92 at 6.2 mW/°C, the SO-8 at 6.5 mW/°C, the SOT-23 at 2.2 mW/°C and the micro SMD at 3mW/°C.

Note 5: Deviation of reference input voltage, V<sub>DEV</sub>, is defined as the maximum variation of the reference input voltage over the full temperature range.

# LM431 Electrical Characteristics (Continued)



The average temperature coefficient of the reference input voltage,  ${\it \sim}{\it V}_{REF}$ , is defined as:

$${}_{\varpropto} V_{REF} \frac{ppm}{{}^{\circ}C} = \frac{\pm \left[ \frac{V_{Max} - V_{Min}}{V_{REF} \left( at \ 25 {}^{\circ}C \right)} \right] 10^6}{T_2 - T_1} = \frac{\pm \left[ \frac{V_{DEV}}{V_{REF} \left( at \ 25 {}^{\circ}C \right)} \right] 10^6}{T_2 - T_1}$$

Where:

 $T_2 - T_1 = \text{full temperature change } (0-70^{\circ}\text{C}).$ 

 ${}_{\sim}V_{REF}$  can be positive or negative depending on whether the slope is positive or negative.

Example:  $V_{DEV}$  = 8.0 mV,  $V_{REF}$  = 2495 mV,  $T_2$  –  $T_1$  = 70°C, slope is positive.

$${}_{\propto}\text{V}_{\text{REF}} = \frac{\left[\frac{8.0 \text{ mV}}{2495 \text{ mV}}\right] 10^6}{70^{\circ}\text{C}} = +46 \text{ ppm/}^{\circ}\text{C}$$

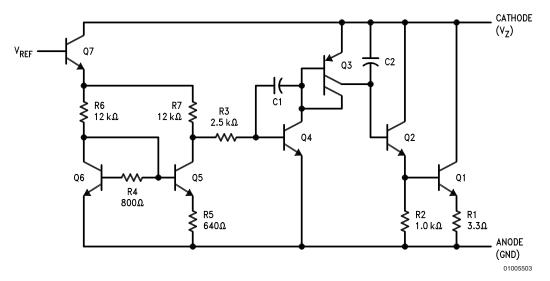
Note 6: The dynamic output impedance,  $r_Z$ , is defined as:

$$r_Z = \frac{\Delta V_Z}{\Delta I_Z}$$

When the device is programmed with two external resistors, R1 and R2, (see Figure 2), the dynamic output impedance of the overall circuit,  $r_Z$ , is defined as:

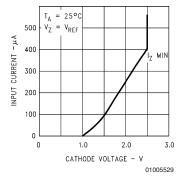
$$r_Z = \frac{\Delta V_Z}{\Delta I_Z} \cong \left[ \, r_Z \left( \, 1 \, + \frac{R1}{R2} \right) \, \right] \label{eq:rz}$$

### **Equivalent Circuit**

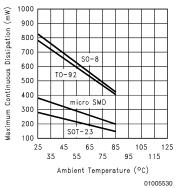


# **Typical Performance Characteristics**

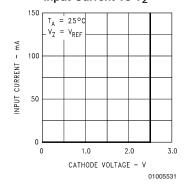
Input Current vs Vz



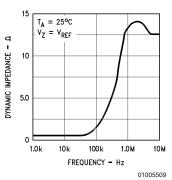




Input Current vs V<sub>z</sub>

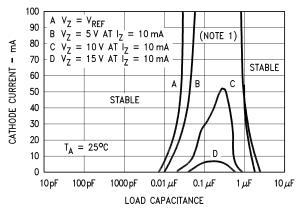


**Dynamic Impedance vs Frequency** 



### Typical Performance Characteristics (Continued)

#### **Stability Boundary Conditions**

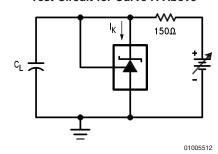


1.0 kΩ
50Ω
I<sub>Z</sub> = 10 mA
01005510

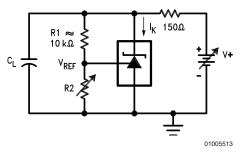
01005511

**Note:** The areas under the curves represent conditions that may cause the device to oscillate. For curves B, C, and D, R2 and V<sup>+</sup> were adjusted to establish the initial  $V_Z$  and  $I_Z$  conditions with  $C_L = 0$ . V<sup>+</sup> and  $C_L$  were then adjusted to determine the ranges of stability.

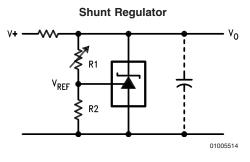
#### **Test Circuit for Curve A Above**



### Test Circuit for Curves B, C and D Above

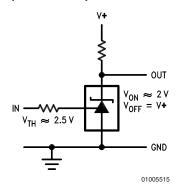


### **Typical Applications**

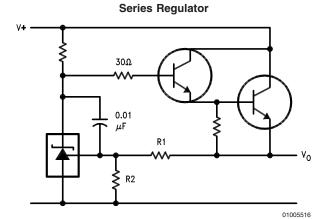


 $V_O \approx \left(1 + \frac{R1}{R2}\right) V_{REF}$ 

### Single Supply Comparator with Temperature Compensated Threshold

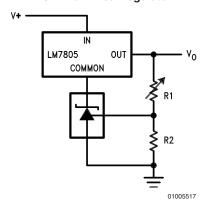


# Typical Applications (Continued)



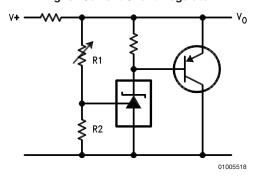
 $V_O \approx \left(1 + \frac{R1}{R2}\right) V_{REF}$ 

# Output Control of a Three Terminal Fixed Regulator

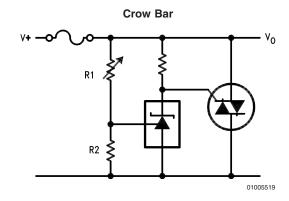


$$V_{O} = \left(1 + \frac{R1}{R2}\right) V_{REF}$$
 $V_{O MIN} = V_{REF} + 5V$ 

### **Higher Current Shunt Regulator**

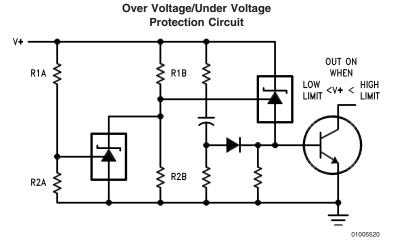


$$V_O \approx \left(1 + \frac{R1}{R2}\right) V_{REF}$$



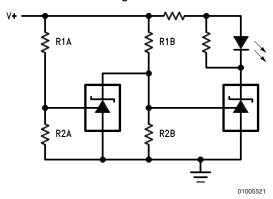
$$V_{LIMIT} \approx \bigg(\ 1 + \frac{R1}{R2}\bigg) V_{REF}$$

# Typical Applications (Continued)



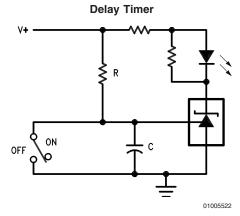
$$\begin{split} & \text{LOW LIMIT} \approx \text{V}_{\text{REF}} \left(1 + \frac{\text{R1B}}{\text{R2B}}\right) + \text{V}_{\text{BE}} \\ & \text{HIGH LIMIT} \approx \text{V}_{\text{REF}} \left(1 + \frac{\text{R1A}}{\text{R2A}}\right) \end{split}$$

### **Voltage Monitor**



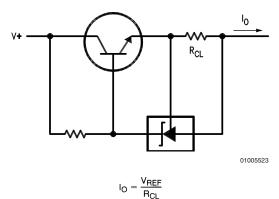
$$\begin{split} \text{LOW LIMIT} &\approx V_{REF} \left( 1 + \frac{\text{R1B}}{\text{R2B}} \right) \quad \begin{array}{l} \text{LED ON WHEN} \\ \text{LOW LIMIT} &< V^+ < \text{HIGH LIMIT} \\ \\ \text{HIGH LIMIT} &\approx V_{REF} \left( 1 + \frac{\text{R1A}}{\text{R2A}} \right) \end{split}$$

### Typical Applications (Continued)

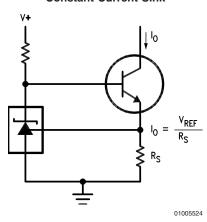


$$DELAY = R \bullet C \bullet \ell n \frac{V+}{(V^+) - V_{REF}}$$

### **Current Limiter or Current Source**



#### **Constant Current Sink**



### **Application Info**

### 1.0 Mounting

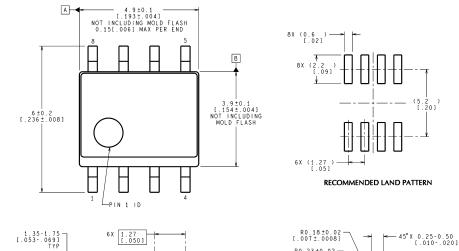
To ensure that the geometry of the micro SMD package maintains good physical contact with the printed circuit board, pin A1 (NC) must be soldered to the pcb. Please see AN-1112 for more detailed information regarding board mounting techniques for the micro SMD package.

### 2.0 LM431 micro SMD Light Sensitivity

When the LM431 micro SMD package is exposed to bright sunlight, normal office fluorescent light, and other LED's and lasers, it operates within the guaranteed limits specified in the electrical characteristics table.

# Physical Dimensions inches (millimeters) unless otherwise noted

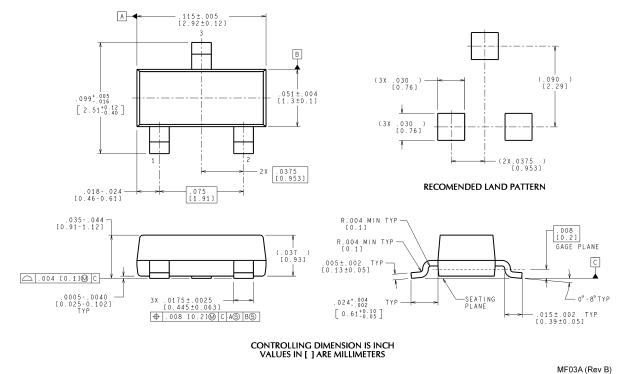
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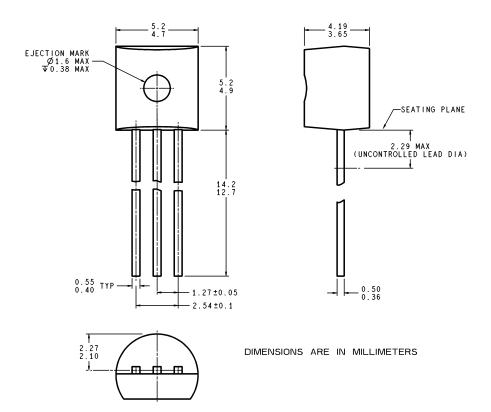
M08A (Rev K)

8-Pin SOIC
NS Package Number M08A



SOT-23 Molded Small Outline Transistor Package (M3) NS Package Number MF03A

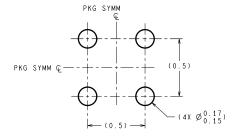
# Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



ZO3A (Rev G)

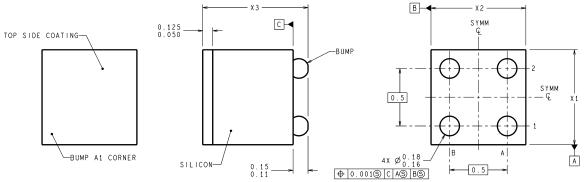
NS Package Number Z03A

### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

#### LAND PATTERN RECOMMENDATION



NOTES: UNLESS OTHERWISE SPECIFIED

- 1. EPOXY COATING
- 2. 63Sn/37Pb EUTECTIC BUMP
- 3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
- 4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION, REMAINING PINS ARE NUMBERED.
- 5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
- 6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BA.

4-Bump micro SMD X1 = 0.777 X2 = 0.904 X3 = 0.850**NS Package Number BPA04AFB** 

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